



SXTA42

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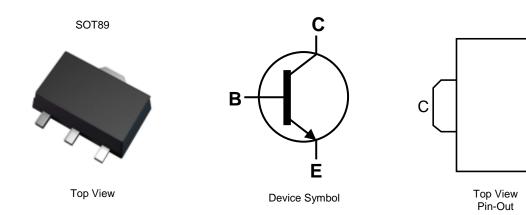
300V NPN HIGH VOLTAGE TRANSISTOR IN SOT89

Features

- BV_{CEO} > 300V
- I_C = 500mA High Continuous Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)



Ordering Information (Note 4)

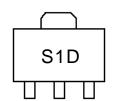
Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
SXTA42TA	S1D	7	12	1,000
SXTA42TC	S1D	13	12	4,000
SXTA42-13R	S1D	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT89



S1D = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	300	V
Collector-Emitter Voltage	$V_{\sf CEO}$	300	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	lc	500	mA

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector Power Dissipation	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	300	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	300	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	_	_	0.1	μA	V _{CB} = 200V
Emitter Cut-Off Current	I _{EBO}	_	_	0.1	μA	V _{EB} = 6V
		25	_	_	_	I _C = 1mA, V _{CE} = 10V
DC Current Transfer Static Ratio (Note 6)	h_{FE}	40	_	_		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}$
		40	_	_	_	$I_C = 30mA, V_{CE} = 10V$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	_	_	0.5	V	$I_C = 20 \text{mA}, I_B = 2 \text{mA}$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	_	_	0.9	V	$I_C = 20\text{mA}, I_B = 2\text{mA}$
Transitional Frequency	f⊤	50	_	_	MHz	$I_C = 10$ mA, $V_{CE} = 20$ V f = 20MHz
Output Capacitance	C _{obo}	_	_	6	pF	V _{CB} = 20V, f = 1MHz

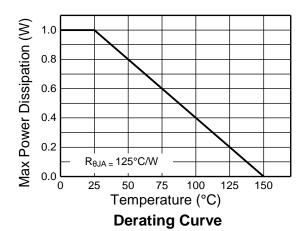
Note:

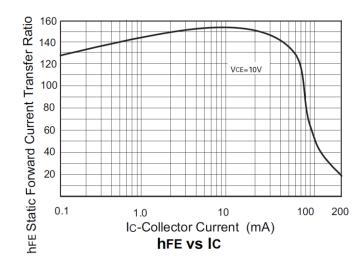
^{5.} For the device mounted on 15mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.

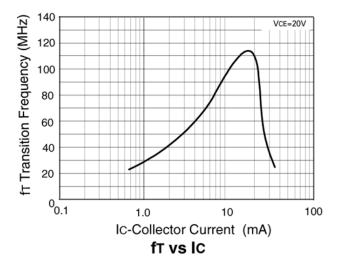
^{6.} Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

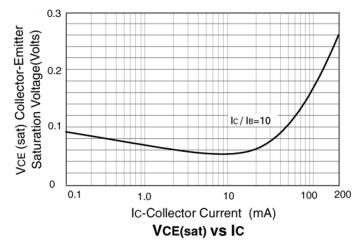


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







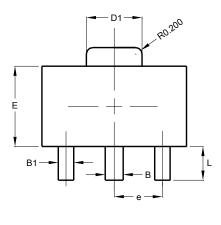


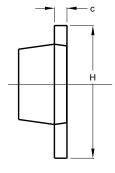


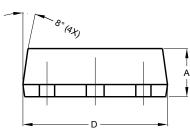
Package Outline Dimensions

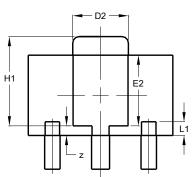
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







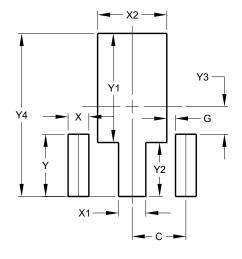


SOT89				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
В	0.50	0.62	0.56	
B1	0.42	0.54	0.48	
С	0.35	0.43	0.38	
D	4.40	4.60	4.50	
D1	1.62	1.83	1.733	
D2	1.61	1.81	1.71	
Е	2.40	2.60	2.50	
E2	2.05	2.35	2.20	
е	-	-	1.50	
Н	3.95	4.25	4.10	
H1	2.63	2.93	2.78	
Ĺ	0.90	1.20	1.05	
L1	0.327	0.527	0.427	
Z	0.20	0.40	0.30	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value		
Dillielisions	(in mm)		
С	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking. Note:



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